

Class A Amplifier with 3 Independent Gain Blocks

LC508 DATA SHEET

FEATURES

- 1 µV input referred noise
- 1.0 to 5 VDC operating range
- 73 dB typical gain (adjustable)
- 0.28 to 2.0 mA range of transducer current
- 1% electrical distortion
- the first and second blocks, or second and third blocks can be DC coupled
- 100 Hz to 50 kHz frequency response
- suitable for active filtering

STANDARD PACKAGING

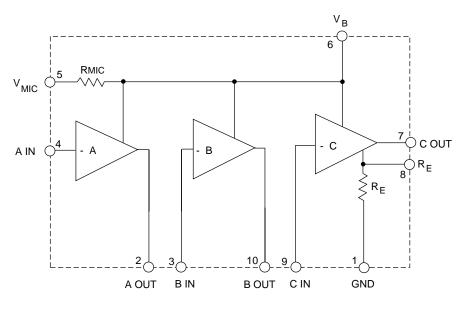
- 10 PIN MICROpac
- •10 pin PLID[®]
- 10 pin SLT
- Chip (52 x 49 mils)

DESCRIPTION

The LC508 is a 10 pin Class A amplifier utilizing Gennum's proprietary low voltage bipolar JFET technology. It consists of 3 single ended, low noise inverting gain blocks. The first two blocks have a typical open loop gain of 50 dB. The closed loop gain is set by the ratio of the feedback resistor to the source impedance. The third block is an open collector output stage with the bias being set by $R_{\rm F}$ and $V_{\rm RF}$ at pin 8 which is 54 mV.

Typically, the gain of the first two blocks is set to 25 dB each, with the third block at 23 dB, giving a total gain of 73 dB.

Gain trim can be accomplished with the use of a feedback resistor on the first block, while the volume control is used as the feedback control on the second block. This gives a volume control range greater than 40 dB.



BLOCK DIAGRAM

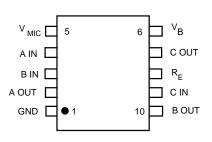
Revision Date: January 2001

Document No. 500 - 61 - 12

ABSOLUTE MAXIMUM RATINGS

PARAMETER	VALUE / UNITS		
Supply Voltage	5V DC		
Power Dissipation	25 mW		
Operating Temperature	-10° to + 40°C		
Storage Temperature	-20° to + 70° C		
CAUTION CLASS 1 ESD SENSITIVITY	6.		



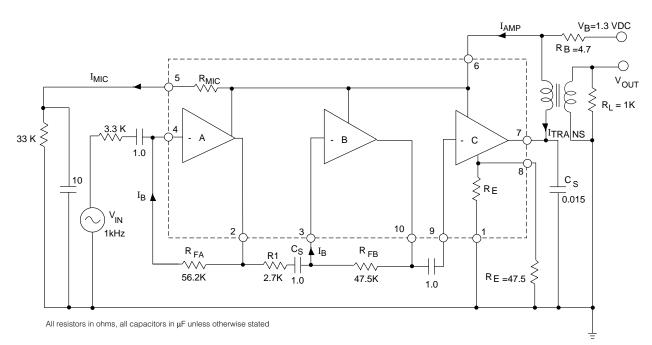


ELECTRICAL CHARACTERISTICS

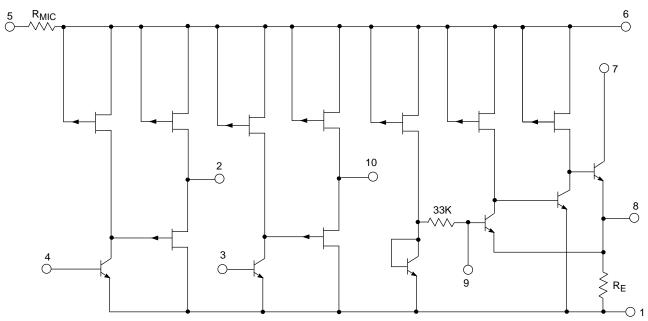
Conditions: Supply Voltage =1.3 VDC, Frequency = 1 kHz, Temperature = 25 °C

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
Gain (Closed Loop)	A _{CL}	V _{OUT} = 500 VRMS	69	73	77	dB
Amplifier Current	$\mathrm{I}_{\mathrm{AMP}}$	$I_{AMP} = I_A + I_{MIC}$	160	245	340	μA
Transducer Current	I _{TRANS H}	R _E = 47.5	1.1	1.3	1.7	mA
Transducer Current	I _{TRANS L}	R _E = ∞	200	275	350	μA
Distortion	THD	V _{OUT} = 500 VRMS	-	1	4	%
Input Referred Noise	IRN	NFB 0.2 to 10kHz at 12dB/Oct	-	1	2	μV
Stable with Battery Resistance to	R _B		-	-	22	Ω
Input Bias Current	I_B		-50	0	50	nA
On Chip Emitter Resistor	R _E		-	200	-	Ω
Emitter Bias Voltage (pin 8)	V _{RE}		-	54	-	mV
Microphone Decoupling Resistor	R _{MIC}		-	4	-	kΩ

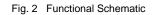
All switches and parameters remain as shown in Test Circuit unless otherwise stated in Conditions column.











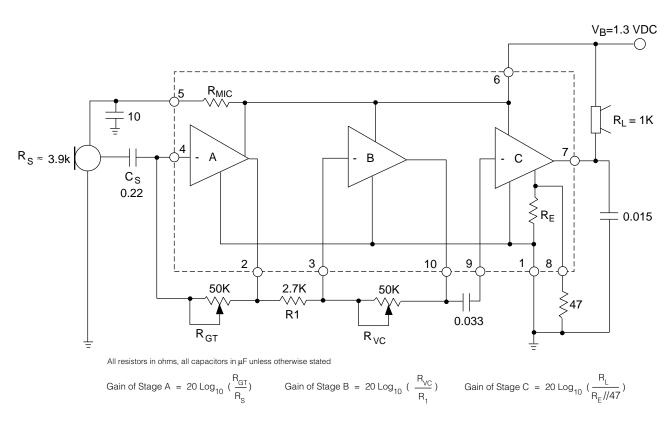
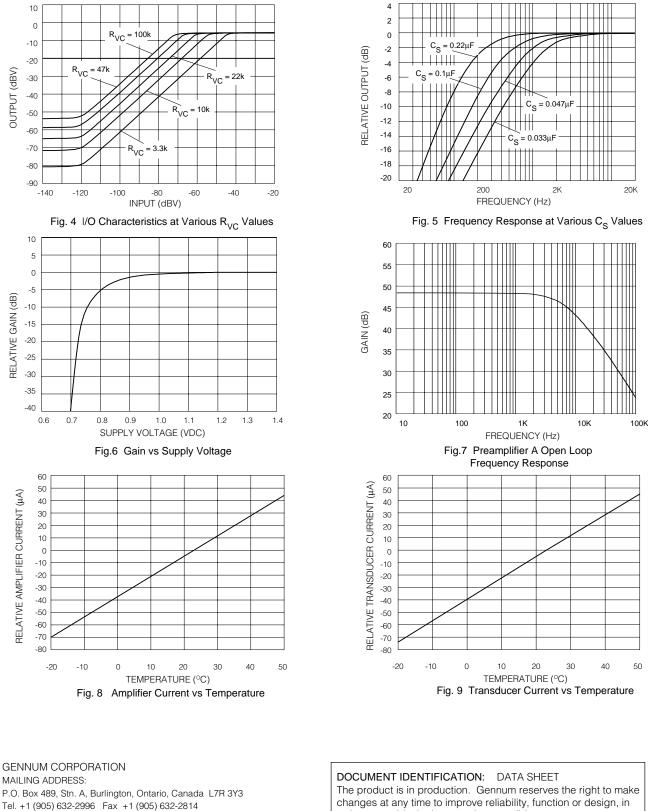


Fig. 3 Typical Hearing Aid Application



970 Fraser Drive, Burlington, Ontario, Canada L7L 5P5

GENNUM JAPAN CORPORATION

SHIPPING ADDRESS:

C-101, Miyamae Village, 2-10-42 Miyamae, Suginami-ku, Tokyo 168-0081, Tel. +81 (3) 3334-7700 Fax: +81 (3) 3247-8839 Japan

changes at any time to improve reliability, function or design, in order to provide the best product possible.

Printed in Canada.

REVISION NOTES:

Changes to standard packaging information

Gennum Corporation assumes no responsibility for the use of any circuits described herein and makes no representations that they are free from patent infringement. © Copyright March 1983 Gennum Corporation. All rights reserved.